Discrete POWER & Signal **Technologies**

MPSL51

FAIRCHILD SEMICONDUCTOR TM

MPSL51



PNP General Purpose Amplifier

This device is designed for use as general purpose amplifiers and switches requiring high voltages. Sourced from Process 74. See 2N5401 for characteristics.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	100	V
V _{CBO}	Collector-Base Voltage 100		V
V _{EBO}	Emitter-Base Voltage	4.0	V
Ic	Collector Current - Continuous 200		mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

 $R_{\theta JA}$

Thermal Resistance, Junction to Ambient

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

ormal Charactoristics

Thermal Characteristics TA = 25°C unless otherwise noted			
Symbol	Characteristic	Max	Units
		MPSL51	
P _D	Total Device Dissipation	625	mW
	Derate above 25°C	5.0	mW/∘C
R _{θJC}	Thermal Resistance, Junction to Case	83.3	°C/W

200

°C/W

PNP General Purpose Amplifie

(continued)

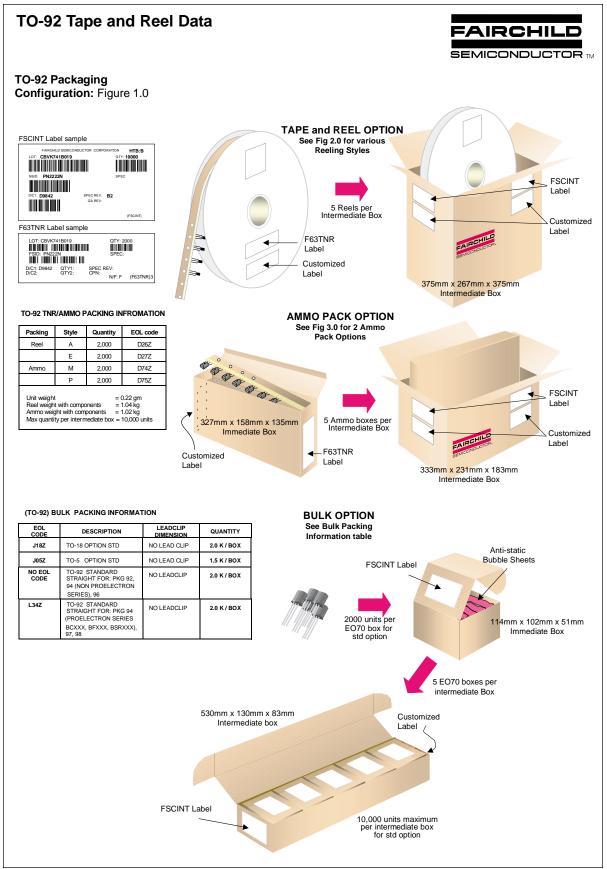
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Electri	Electrical Characteristics TA = 25°C unless otherwise noted					
Symbol	Parameter	Test Conditions	Min	Max	Units	
OFF CHA	RACTERISTICS					
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage*	$I_{\rm C} = 1.0 {\rm mA}, I_{\rm B} = 0$	100		V	
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{\rm C} = 100 \ \mu \text{A}, I_{\rm E} = 0$	100		V	
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_{E} = 10 \ \mu A, I_{C} = 0$	4.0		V	
I _{CBO}	Collector Cutoff Current	$V_{CB} = 50 \text{ V}, \text{ I}_{E} = 0$		1.0	μA	
I _{EBO}	Emitter Cutoff Current	$V_{EB} = 3.0 \text{ V}, I_{C} = 0$		100	nA	
ON CHAR	ACTERISTICS*	-				
h _{FE}	DC Current Gain	$V_{CE} = 5.0 \text{ V}, I_{C} = 50 \text{ mA}$	40	250		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_{C} = 10 \text{ mA}, I_{B} = 1.0 \text{ mA}$ $I_{C} = 50 \text{ mA}, I_{B} = 5.0 \text{ mA}$		0.25 0.3	V V	
$V_{\text{BE}(\text{sat})}$	Base-Emitter Saturation Voltage	$I_{C} = 10 \text{ mA}, I_{B} = 1.0 \text{ mA}$ $I_{C} = 50 \text{ mA}, I_{B} = 5.0 \text{ mA}$		1.2 1.2	V V	

SMALL SIGNAL CHARACTERISTICS

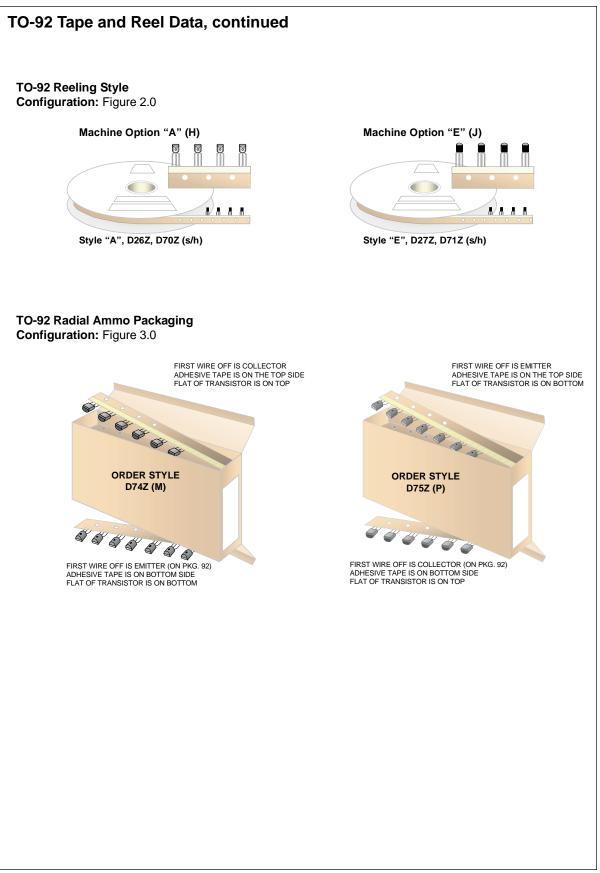
C _{ob}	Output Capacitance	V _{CB} = 10 V, f = 1.0 MHz		8.0	pF
h _{fe}	Small-Signal Current Gain	$I_{C} = 1.0 \text{ mA}, V_{CE} = 10 \text{ V},$ f = 1.0 kHz	20		
f _T	Current Gain - Bandwidth Product	$V_{CE} = 10 \text{ V}, I_{C} = 10 \text{ mA},$	60		MHz

*Pulse Test: Pulse Width $\leq 300\,$ µs, Duty Cycle $\leq 2.0\%$



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